

## D-Band Reflective FET Switch

110-170 GHz/SPDT/ WR-06

Model: TMSPDT-110170-06

The TMSPDT-110170-06 is a D-Band switch with a TTL driver that operates between 110 and 170 GHz. The SPDT switch offers 23 dB port-to-port isolation with a typical switching speed of 100 nanoseconds. The input and output connectors of the switch are WR-06.

### Features:

- Frequency range: 110-170GHz
- Low Insertion Loss: 5.5 dB
- Power Handling : 30 dBm
- High Isolation
- Switch Type: Reflective

### Applications:

- Communication Systems
- Automatic Test Equipment
- Switching Network

### Electrical Characteristics:

Parameter	Min	Typ	Max	Units
Frequency range	110-170			GHz
Insertion Loss		5.5		dB
Isolation		23		dB
Switch Speed		100		ns
Input VSWR		3.6		:1
Output VSWR		2.5		:1
P1dB Output P1dB		25		dBm
DC Voltage		+5		V DC
Control Voltage TTL	"0"=Low;"1"=High			V
DC Supply Current		-100		mA
Switch type	Reflective			

### Absolute Maximum Ratings :

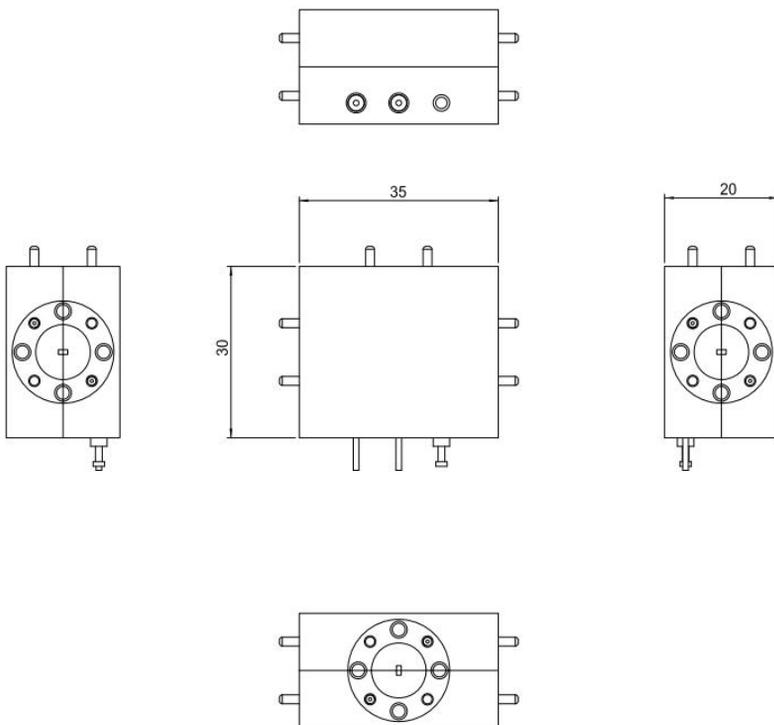
Description	Parameter	Units
Supply Bias Voltage	+5 (+5%)	V
RF Input Power	30	dBm
ESD sensitivity (HBm)	Class 0, passed 150V	

### Mechanical Specifications:

Description	Parameter	Units
Input /Output Connector	WR-06/UG-387/U	
Control Bias	Solder Pin	
Size	35*30*20	mm

### Outline Drawing:

Unit:mm



Truth Table	
TTL Control Input	Signal Path State
0	J0-J1
1	J0-J2

TTL Control Voltages &VDD	
Stage	Bias Condition
VDD	+5V (± 5%)
Low (0)	0 to 0.8Vdc
High (1)	3.3 to +5.0Vdc



ESD Protection: Strictly adhere to ESD precautions to prevent electrostatic damage.

### Environmental Conditions:

Parameter	Min	Typ	Max	Units
Operating Temperature	-45		+85	°C
Non-operating Temperature	-55		+125	°C
Relative humidity		95		%
Altitude	10,000			feet
Shock / Vibration(MIL-STD-810F)	25g rms (15 degree 2KHz) endurance, 1 hour per axis			
Shock(non operating)	20G for 11msc half sin wave,3 axis both directions			

### Ordering Information:

Base Number	Description	Revision
TMSPDT-110170-06	D-Band Reflective FET Switch 110-170 GHz,SPDT,WR-06	Rev.1.1